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To:	Examiner C.Q. Nguyen	From:	Leslie S. Szivos, Ph.D.
Fax:	703 872-9306	Pages:	1 Including cover sheet
Phone:		Date:	12/14/2004
Re:	US Application Serial No. 10/700,085 Filing Date: 11/03/2003 Docket No. YOR920030586US1 (17201)	CC:	

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1. Response Under 37 C.F.R. §1.111 and §1.143
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Applicant(s): Tze-Chiang Chen, et al.

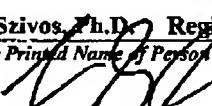
Docket No.

Y0R920030586US1 (17201)

Application No.
10/700,085Filing Date
11/3/2003Examiner
C.Q. NguyenGroup Art Unit
2811Invention: **METHOD FOR FABRICATING SiGe-ON-INSULATOR (SGOI) AND Ge-ON-INSULATOR (GOI) SUBSTRATES**

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Docket No.
Y0R920030586US1 (17201)

In Re Application Of: **Tze-Chiang Chen, et al.**

Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen	Customer No. 23389	Group Art Unit 2811	Confirmation No. 2805
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Title: **METHOD FOR FABRICATING SiGe-ON-INSULATOR (SGOI) AND Ge-ON-INSULATOR (GOI) SUBSTRATES**

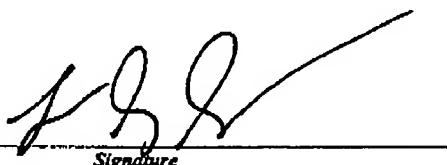
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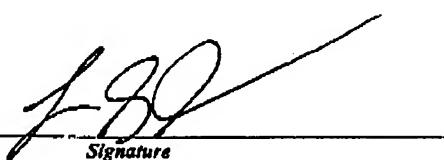
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